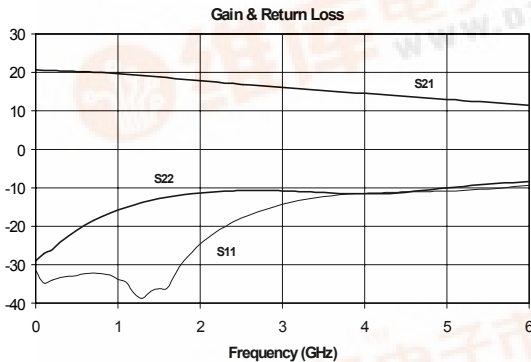




Product Description

Sirenza Microdevices' SBA-5089 is a high performance InGaP/GaAs Heterojunction Bipolar Transistor MMIC Amplifier. A Darlington configuration designed with InGaP process technology provides broadband performance up to 5 GHz with excellent thermal performance. The heterojunction increases breakdown voltage and minimizes leakage current between junctions. Cancellation of emitter junction non-linearities results in higher suppression of intermodulation products. Only a single positive supply voltage, DC-blocking capacitors, a bias resistor, and an optional RF choke are required for operation.



SBA-5089

DC-5 GHz, Cascadable InGaP/GaAs HBT MMIC Amplifier



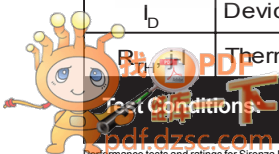
Product Features

- IP3 = 34.0dBm @ 1950MHz
- Pout=13.0 dBm @-45dBc ACP IS-95 1950MHz
- Robust 1000V ESD, Class 1C
- Operates From Single Supply
- Patented Thermal Design

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS
- IF Amplifier
- Wireless Data, Satellite Terminals

Symbol	Parameter	Units	Frequency	Min.	Typ.	Max.
G	Small Signal Gain	dB	850 MHz 1950 MHz	18.5 16.5	20.0 18.0	21.5 19.5
P _{1dB}	Output Power at 1dB Compression	dBm	850 MHz 1950 MHz	18.0	19.7 19.5	
OIP ₃	Output Third Order Intercept Point	dBm	850 MHz 1950 MHz	32.0	36.0 34.0	
P _{OUT}	Output Power @ -45dBc ACP IS-95 9 Forward Channels	dBm	1950 MHz		13.0	
Bandwidth	Determined by Return Loss (>10dB)	MHz			4400	
IRL	Input Return Loss	dB	1950 MHz	14.0	20.0	
ORL	Output Return Loss	dB	1950 MHz	9.0	11.0	
NF	Noise Figure	dB	1950 MHz		4.5	5.5
V _D	Device Operating Voltage	V		4.5	4.9	5.3
I _D	Device Operating Current	mA		72	80	88
R _{th(j-l)}	Thermal Resistance (junction to lead)	°C/W			70	



Test Conditions:
 $V_S = 8\text{ V}$
 $R_{BIAS} = 39\text{ Ohms}$
 $I_D = 80\text{ mA Typ.}$
 $T_L = 25^\circ\text{C}$

OIP₃ Tone Spacing = 1 MHz, Pout per tone = 0 dBm
 $Z_S = Z_L = 50\text{ Ohms}$



SBA-5089 DC-5 GHz Cascadable MMIC Amplifier

Typical RF Performance at Key Operating Frequencies

Symbol	Parameter	Unit	Frequency (MHz)					
			100	500	850	1950	2400	3500
G	Small Signal Gain	dB	20.5	20.2	19.9	18.0	17.1	15.3
OIP ₃	Output Third Order Intercept Point	dBm	36.3	35.8	36.0	34.0	32.7	30.9
P _{1dB}	Output Power at 1dB Compression	dBm	19.8	19.8	19.7	19.5	18.8	17.1
IRL	Input Return Loss	dB	29	27	25	20	17	11.8
ORL	Output Return Loss	dB	27	21	17	11	11	11
S ₂₁	Reverse Isolation	dB	22	22	23	23	23	23
NF	Noise Figure	dB	4.1	4.3	4.2	4.5	---	---

Test Conditions: $V_S = 8\text{ V}$, $I_D = 80\text{ mA}$ Typ., OIP_3 Tone Spacing = 1 MHz, P_{out} per tone = 0 dBm
 $R_{BIAS} = 39\text{ Ohms}$, $T_L = 25^\circ\text{C}$, $Z_S = Z_L = 50\text{ Ohms}$

Absolute Maximum Ratings

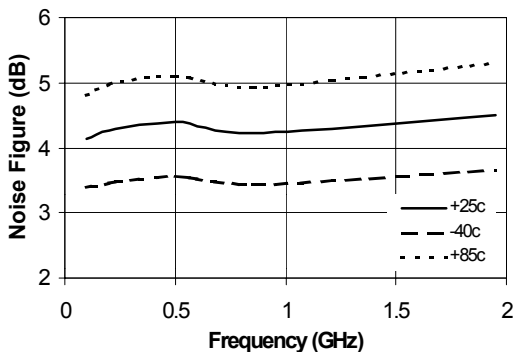
Parameter	Absolute Limit
Max. Device Current (I_D)	130 mA
Max. Device Voltage (V_D)	6 V
Max. RF Input Power	+17 dBm
Max Operating Dissipated Power	0.65 W
Max. Junction Temp. (T_J)	+150°C
Operating Temp. Range (T_L)	-40°C to +85°C
Max. Storage Temp.	+150°C

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

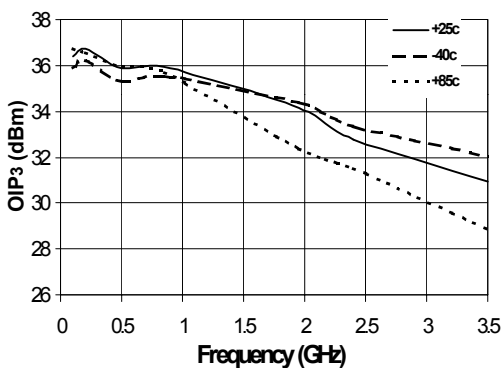
Bias Conditions should also satisfy the following expression:

$$I_D V_D < (T_J - T_L) / R_{TH} \quad T_L = T_{LEAD}$$

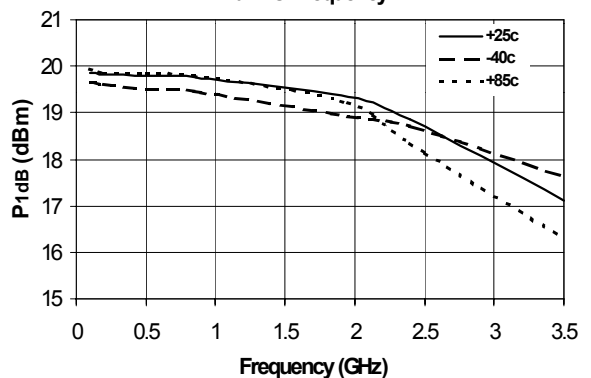
Noise Figure vs. Frequency



OIP3 vs. Frequency



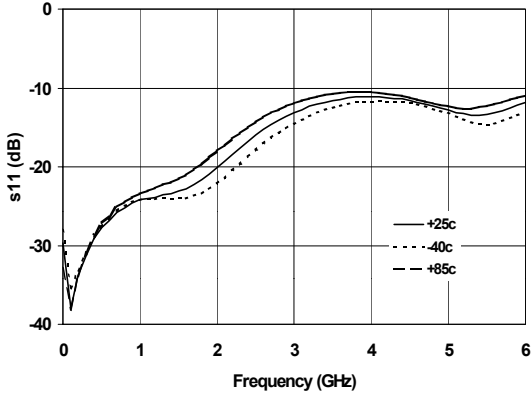
P1dB vs. Frequency



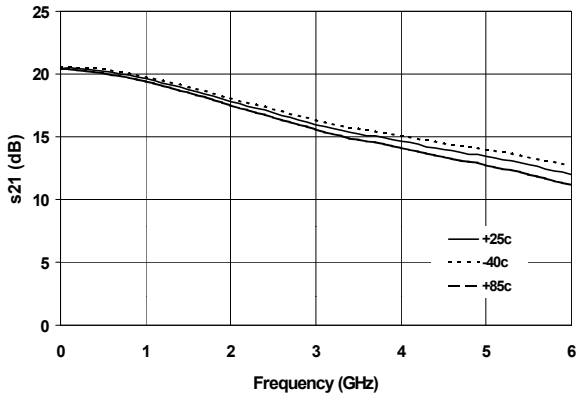


SBA-5089 DC-5 GHz Cascadable MMIC Amplifier

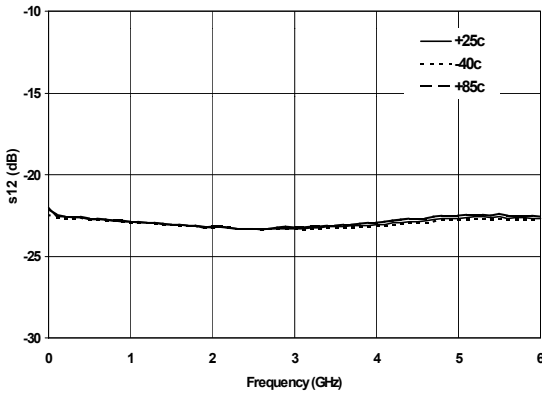
$|S_{11}|$ vs. Frequency



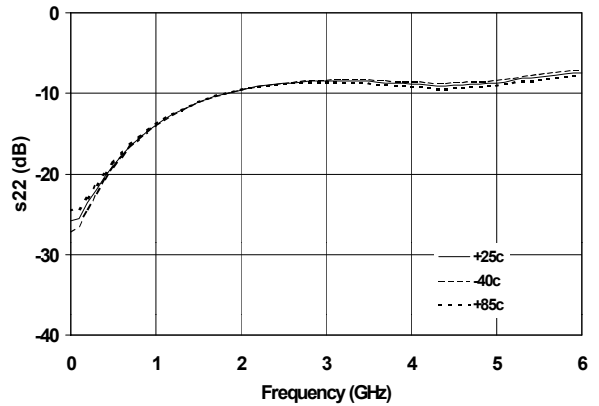
$|S_{21}|$ vs. Frequency



$|S_{12}|$ vs. Frequency

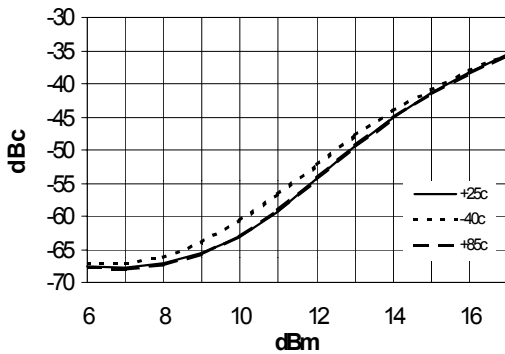


$|S_{22}|$ vs. Frequency



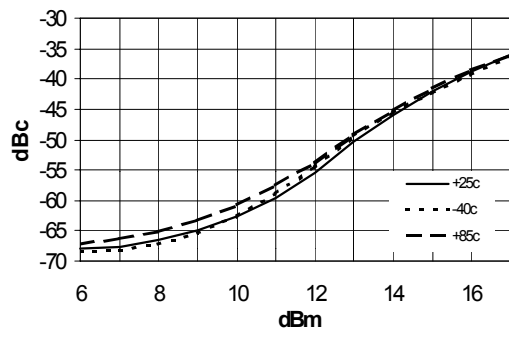
IS-95 @ 850MHz

Adj. Channel Pwr. vs. Channel Output Pwr.

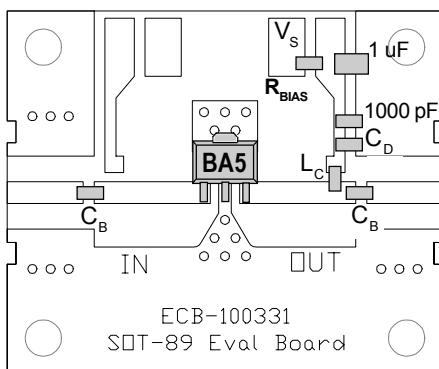
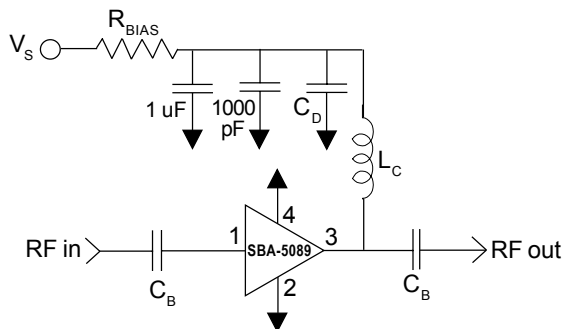


IS-95 @ 1950MHz

Adj. Channel Pwr. vs. Channel Output Power

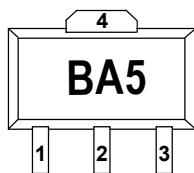


Basic Application Circuit



Part Identification Marking

The part will be marked with an "BA5" designator on the top surface of the package.



Application Circuit Element Values

Reference Designator	Frequency (Mhz)				
	500	850	1950	2400	3500
C _B	220 pF	100 pF	68 pF	56 pF	39 pF
C _D	100 pF	68 pF	22 pF	22 pF	15 pF
L _C	68 nH	33 nH	22 nH	18 nH	15 nH

Recommended Bias Resistor Values for I_D=80mA

$$R_{BIAS} = (V_S - V_D) / I_D$$

Supply Voltage (V _S)	7.5 V	8 V	10 V	12 V
R _{BIAS}	33 Ω	39 Ω	68 Ω	91 Ω

Note: R_{BIAS} provides DC bias stability over temperature.

Mounting Instructions

1. Solder the copper pad on the backside of the device package to the ground plane.
2. Use a large ground pad area with many plated through-holes as shown.
3. We recommend 1 or 2 ounce copper. Measurement for this data sheet were made on a 31 mil thick FR-4 board with 1 ounce copper on both sides.

Pin #	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
2, 4	GND	Connection to ground. Use via holes for best performance to reduce lead inductance as close to ground leads as possible.
3	RF OUT/ BIAS	RF output and bias pin. DC voltage is present on this pin, therefore a DC blocking capacitor is necessary for proper operation.

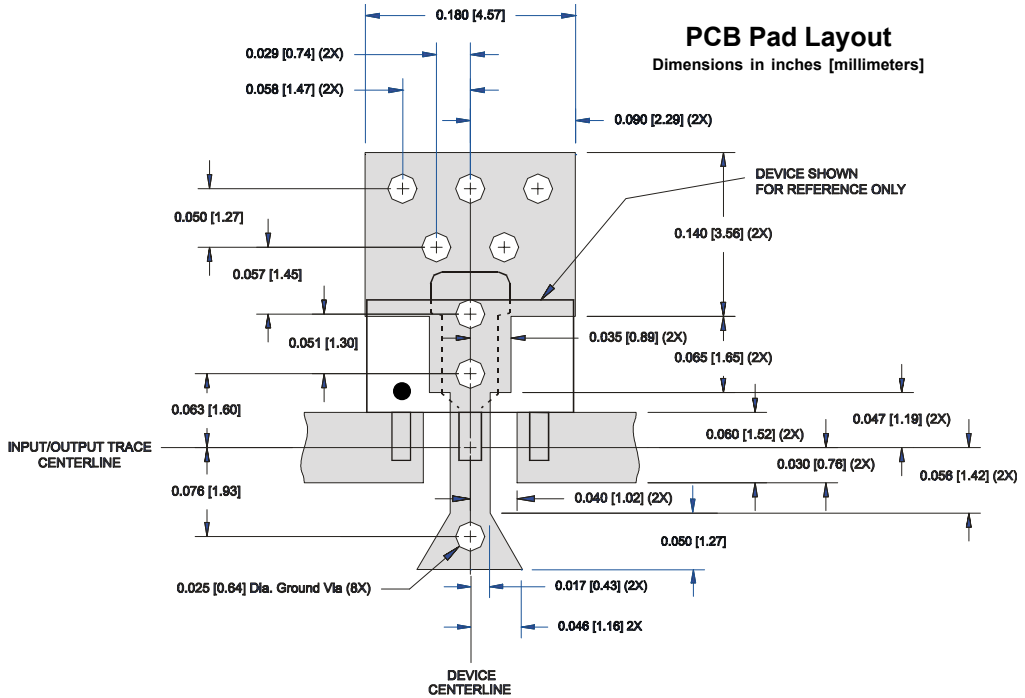
Part Number Ordering Information

Part Number	Reel Size	Devices/Reel
SBA-5089	7"	1000



Caution: ESD sensitive

Appropriate precautions in handling, packaging and testing devices must be observed.



Nominal Package Dimensions

Dimensions in inches [millimeters]

Refer to package drawing posted at www.sirenza.com for tolerances.

